BAS40-04LT1G, SBAS40-04LT1G

Dual Series Schottky Barrier Diode

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

Features

- Extremely Fast Switching Speed
- Low Forward Voltage
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Reverse Voltage	V _R	40	V
Forward Power Dissipation @ T _A = 25°C Derate above 25°C	P _F	225 1.8	mW mW/°C
Operating Junction and Storage Temperature Range	T _{J,} T _{stg}	-55 to +150	°C
Forward Continuous Current	I _{FM}	120	mA
Single Forward Current $t \le 1 s$ $t \le 10 ms$	I _{FSM}	200 600	mA
Thermal Resistance (Note 1) Junction–to–Ambient (Note 2)	$R_{\theta JA}$	508 311	°C/W

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. FR-4 @ minimum pad.
- 2. FR-4 @ 1.0 x 1.0 in pad.



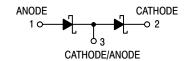
ON Semiconductor®

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40 VOLTS SCHOTTKY BARRIER DIODES



SOT-23 (TO-236) CASE 318 STVI F 11



MARKING DIAGRAM



CB = Specific Device Code

M = Date Code*■ Pb-Free Package

(Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
BAS40-04LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel
SBAS40-04LT1G	SOT-23 (Pb-Free)	3,000 / Tape & Reel

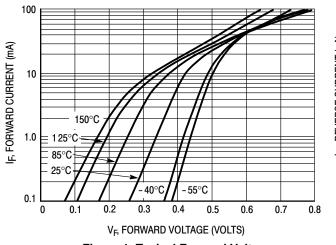
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

BAS40-04LT1G, SBAS40-04LT1G

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Reverse Breakdown Voltage (I _R = 10 μA)	V _{(BR)R}	40	_	V
Total Capacitance (V _R = 1.0 V, f = 1.0 MHz)	Ст	-	5.0	pF
Reverse Leakage (V _R = 25 V)	I _R	-	1.0	μΑ
Forward Voltage (I _F = 1.0 mA)	V _F	-	380	mV
Forward Voltage (I _F = 10 mA)	V _F	-	500	mV
Forward Voltage (I _F = 40 mA)	V _F	-	1.0	V

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



T_A = 150°C IR, REVERSE CURRENT (uA) 125°C 10 85°C 1.0 0.1 25°C 0.01 0.001 5.0 20 25 10 15 V_R, REVERSE VOLTAGE (VOLTS)

Figure 1. Typical Forward Voltage

Figure 2. Reverse Current versus Reverse Voltage

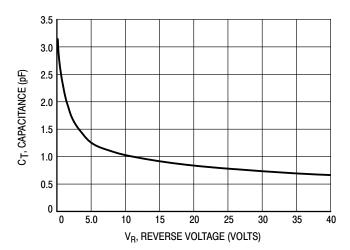


Figure 3. Typical Capacitance



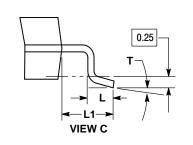


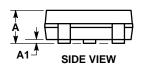
SOT-23 (TO-236) CASE 318-08 **ISSUE AS**

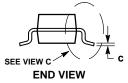
DATE 30 JAN 2018

SCALE 4:1 D Ε **←** 3X b

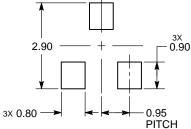
TOP VIEW







RECOMMENDED SOLDERING FOOTPRINT

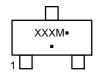


3. ANODE

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH.
 MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL
- 4. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH,

	MILLIMETERS				INCHES	
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.89	1.00	1.11	0.035	0.039	0.044
A1	0.01	0.06	0.10	0.000	0.002	0.004
b	0.37	0.44	0.50	0.015	0.017	0.020
С	0.08	0.14	0.20	0.003	0.006	0.008
D	2.80	2.90	3.04	0.110	0.114	0.120
E	1.20	1.30	1.40	0.047	0.051	0.055
е	1.78	1.90	2.04	0.070	0.075	0.080
L	0.30	0.43	0.55	0.012	0.017	0.022
L1	0.35	0.54	0.69	0.014	0.021	0.027
HE	2.10	2.40	2.64	0.083	0.094	0.104
Т	0°		10°	0°		10°

GENERIC MARKING DIAGRAM*



XXX = Specific Device Code

M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

	DIMENSIONS: MILLIM	ETERS	
STYLE 1 THRU 5:	STYLE 6:	STYLE 7:	STYLE 8:

STYLE TIMKU 5:	STYLE 6:	SIYLE /:	STYLE 8:
CANCELLED	PIN 1. BASE	PIN 1. EMITTER	PIN 1. ANODE
	EMITTER	2. BASE	NO CONNECTION
	COLLECTOR	COLLECTOR	CATHODE

STYLE 9	:	STYLE 10:	STYLE 11:	STYLE 12:	STYLE 13:	STYLE 14:
PIN 1.	ANODE	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. CATHODE	PIN 1. SOURCE	PIN 1. CATHODE
2.	ANODE	SOURCE	CATHODE	CATHODE	2. DRAIN	2. GATE
3.	CATHODE	GATE	CATHODE-AN	NODE 3. ANODE	3. GATE	ANODE

STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:	STYLE 19:	STYLE 20:
PIN 1. GATE	PIN 1. ANODE	PIN 1. NO CONNECTION	PIN 1. NO CONNECTION	PIN 1. CATHODE	PIN 1. CATHODE
CATHODE	CATHODE	2. ANODE	CATHODE	2. ANODE	ANODE
ANODE	CATHODE	CATHODE	ANODE	CATHODE-ANOD	E 3. GATE

STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:	STYLE 25:	STYLE 26:
PIN 1. GATE	PIN 1. RETURN	PIN 1. ANODE	PIN 1. GATE	PIN 1. ANODE	PIN 1. CATHODE
0 0011005	O OLITPLIT	O ANODE	2 DDAIN	2 CATHODE	2 ANODE

2. SOURCE 3. DRAIN	2. OUTPUT 3. INPUT	2. ANODE 3. CATHODE	2. DRAIN 3. SOURCE	2. CATHODE 3. GATE	2. ANODE 3. NO CONNECTION
STYLE 27: PIN 1. CATHODE	STYLE 28: PIN 1. ANODE				
2. CATHODE	2. ANODE				

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3. CATHODE

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PAGE 2 OF 2

ISSUE	REVISION	DATE
AJ	ADDED STYLE 27. REQ. BY P. LEM.	07 JUL 2004
AK	OBSOLETED -09 VERSION. REQ. BY D. TRUHITTE.	14 SEP 2004
AL	ADDED NOMINAL VALUES AND UPDATED GENERIC MARKING DIAGRAM. REQ. BY HONG XIAO.	27 MAY 2005
AM	REDREW LEAD SIDE VIEW. REQ BY DARRELL TRUHITTE.	26 AUG 2005
AN	REINTRODUCED LABELS FOR DIMENSION C. REQ. BY D. TRUHITTE.	14 OCT 2005
AP	ADDED THETA DEGREE VALUES TO DIMENSION TABLE. REQ. BY D. TRUHITTE.	17 NOV 2009
AR	MODIFIED DIMENSIONS C AND L. REQ. BY M. YOU.	10 OCT 2016
AS	ADDED STYLE 28. REQ. BY E. ESTILLER.	30 JAN 2018

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